
192-BIT AC-PDP DRIVER

DESCRIPTION

The μPD160300 is a high-withstanding-voltage CMOS driver designed for use with a flat display panel such as a PDP, VFD, or EL panel. It consists of a 192-bit bi-directional shift register, 192-bit latch and high-withstanding-voltage CMOS driver. The logic block operates with a 5.0 V power supply and 3.3 V interface so that it can be directly connected to a gate array and microcomputer (CMOS Level Input). The driver block provides a high-withstanding-voltage output: 80 V.

The logic and driver blocks are made of CMOS circuits, consuming lower power.

FEATURES

- 3-ch, 6-ch and 6-ch (3-ch + 3-ch) input port switching is possible using the IBS1 and IBS2 pins
- Many outputs: 192-bit output
- Clock transfer is switchable via the SDS pin between single edge and double edge
- Data control with transfer clock (external) and latch
- High-speed data transfer: $f_{CLK} = 60 \text{ MHz MAX.}$ (at loading of data)
- High withstanding voltage and high drive output: 80 V MAX., +13/-24 mA MAX.
- 3.3 V input interface ($V_{DD1} = 5.0 \text{ V}$)
- High-withstanding-voltage CMOS structure

ORDERING INFORMATION

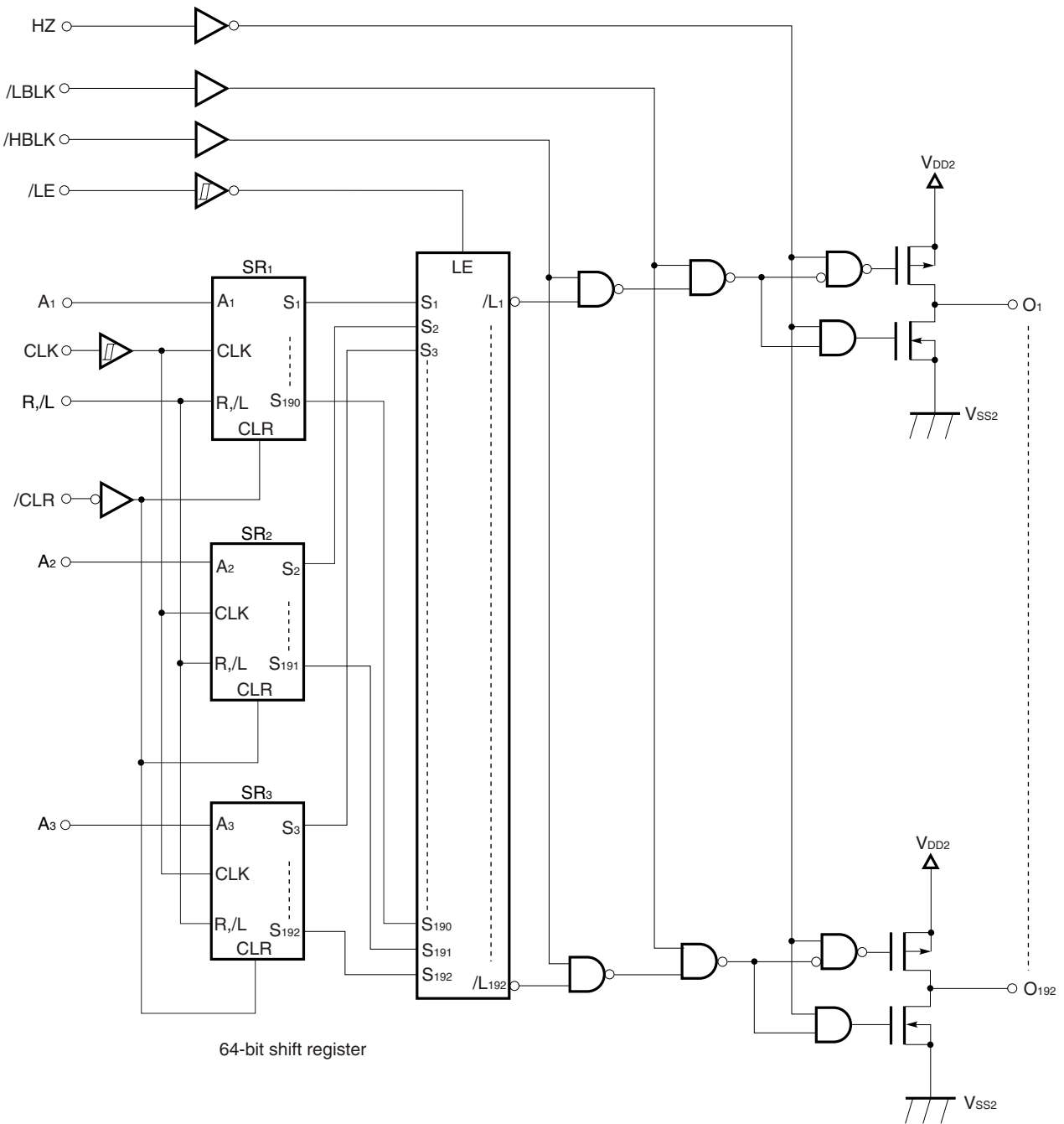
Part Number	Package
μPD160300N-xxx	TCP (TAB package)

Remark The TCP's external shape is customized. To order the required shape, please contact one of our sales representatives.

The information contained in this document is being issued in advance of the production cycle for the product. The parameters for the product may change before final production or NEC Electronics Corporation, at its own discretion, may withdraw the product prior to its production. Not all products and/or types are available in every country. Please check with an NEC Electronics sales representative for availability and additional information.

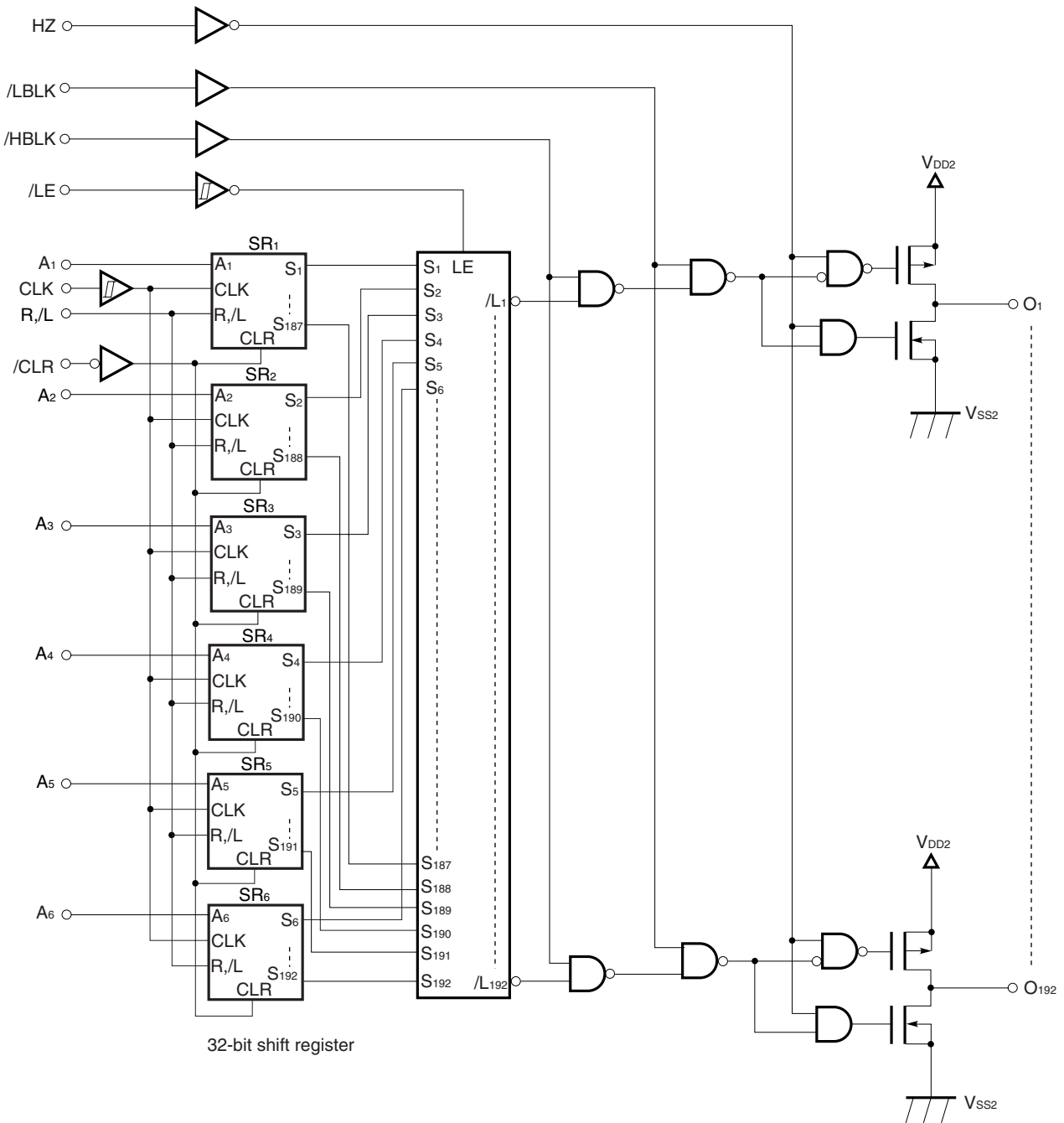
1. BLOCK DIAGRAM

(1) IBS1 = L, IBS2 = H or L: 3-bit input

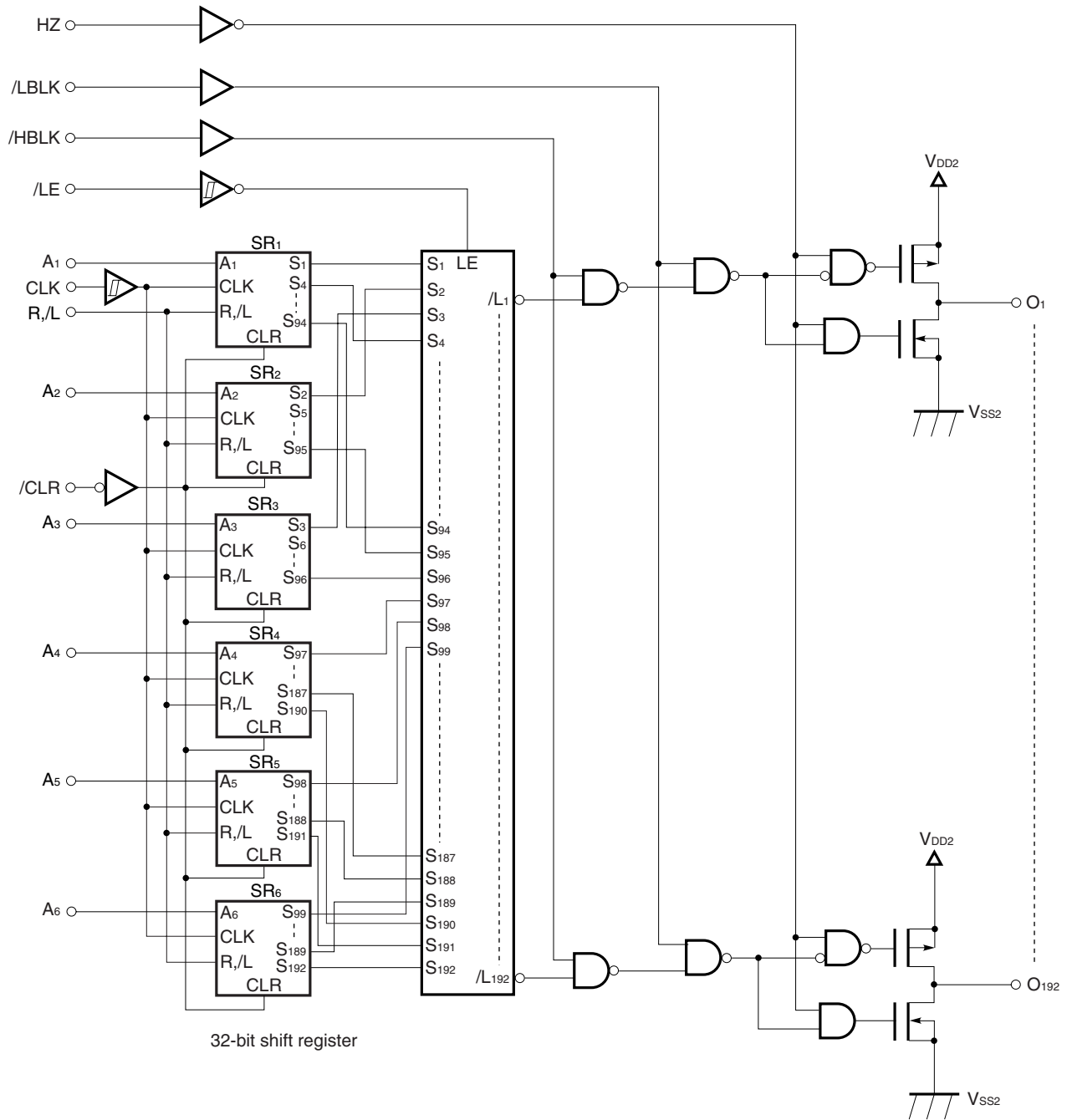


Remark /xxx indicates active low signal.

(2) IBS1 = H, IBS2 = L: 6-bit input

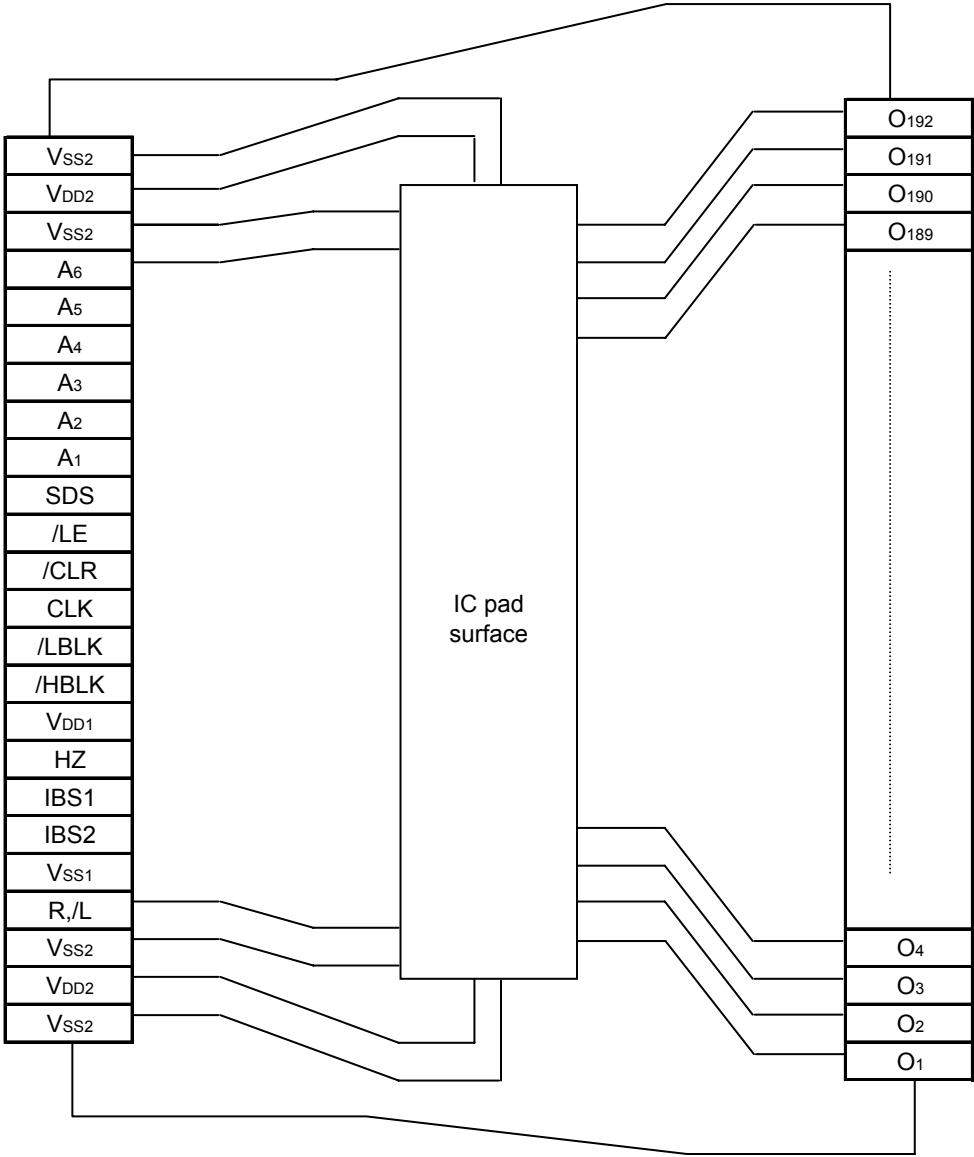


(3) IBS1 = H, IBS2 = H: 6-bit (3-bit + 3-bit) input



2. PIN CONFIGURATION (IC pad surface)

μPD160300N-xxx: TCP (TAB package)



Remark This figure does not specify the TCP package.

3. PIN FUNCTIONS

Symbol	Pin Name	I/O	Description
/LBLK	Low blanking	Input	/LBLK = L: All output = L
/HBLK	High blanking	Input	/HBLK = L: All output = H
/LE	Latch enable	Input	Latch operation performed at the falling edge.
HZ	Output high impedance	Input	HZ = H: All output set to the high-impedance state
/CLR	Register clear	Input	/CLR = L: All shift register data cleared to the low level
A ₁ to A ₃₍₆₎	Data	Input	The A ₁ to A ₃₍₆₎ are Data input pins. The data shift direction is switched inside the R,/L pin.
CLK	Clock	Input	SDS = H: Shift operation is executed at the rising and falling edges SDS = L: Shift operation is executed at the rising edge
R,/L	Shift direction control	Input	The shift direction control pin of shift register. The shift directions of the shift register are as follows. R,/L = H (right shift): SR ₁ : A ₁ → S ₁ ...S ₁₉₀ (SR ₂ to SR ₆ also shift in the same direction.) R,/L = L (left shift): SR ₁ : A ₁ → S ₁₉₀ ...S ₁ (SR ₂ to SR ₆ also shift in the same direction.) Refer to 5. INTERNAL REGISTER.
IBS ₁ , IBS ₂	Input mode switch	Input	IBS ₁ = H, IBS ₂ = H: 6-bit (3-bit + 3-bit) input, Length of shift register: 32-bit IBS ₁ = H, IBS ₂ = L: 6-bit input, Length of shift register: 32-bit IBS ₁ = L, IBS ₂ = H or L: 3-bit input, Length of shift register: 64-bit
SDS	Clock edge switch	Input	SDS = H: Shift operation is executed at the rising and falling edges of CLK (double edge) SDS = L: Shift operation is executed at the rising edge of CLK (single edge)
O ₁ to O ₁₉₂	High withstanding voltage	Output	70 V
V _{DD1}	Logic power supply	–	5 V ± 5%
V _{DD2}	Driver power supply	–	15 to 70 V
V _{SS1}	Logic ground	–	Connect to system ground
V _{SS2}	Driver ground	–	Connect to system ground

Caution In 3-bit input mode, unused input pins must be held at the low level or high level.

4. TRUTH TABLE

Shift Register Block

Input			Shift Register
R,/L	SDS	CLK	
H	H	↑ or ↓	Right shift operation is executed.
H	H	H or L	Hold
H	L	↑	Right shift operation is executed.
H	L	H or L	Hold
L	H	↑ or ↓	Left shift operation is executed.
L	H	H or L	Hold
L	L	↑	Left shift operation is executed.
L	L	H or L	Hold

Latch Block

/LE	Output State of Latch Section (/L _n)
↓	Latch S _n data
H or L	Hold latch (output) data

Driver Block

A	/HBLK	/LBLK	HZ	Output State of Driver Block
				O ₁ to O ₁₉₂
x	L	H	L	All driver output: H
x	x	L	L	All driver output: L
x	x	x	H	All driver output: High-impedance
L	H	H	L	L
H	H	H	L	H

Remark x: H or L

5. INTERNAL REGISTER

Shift Direction (R,/L = H, right shift)

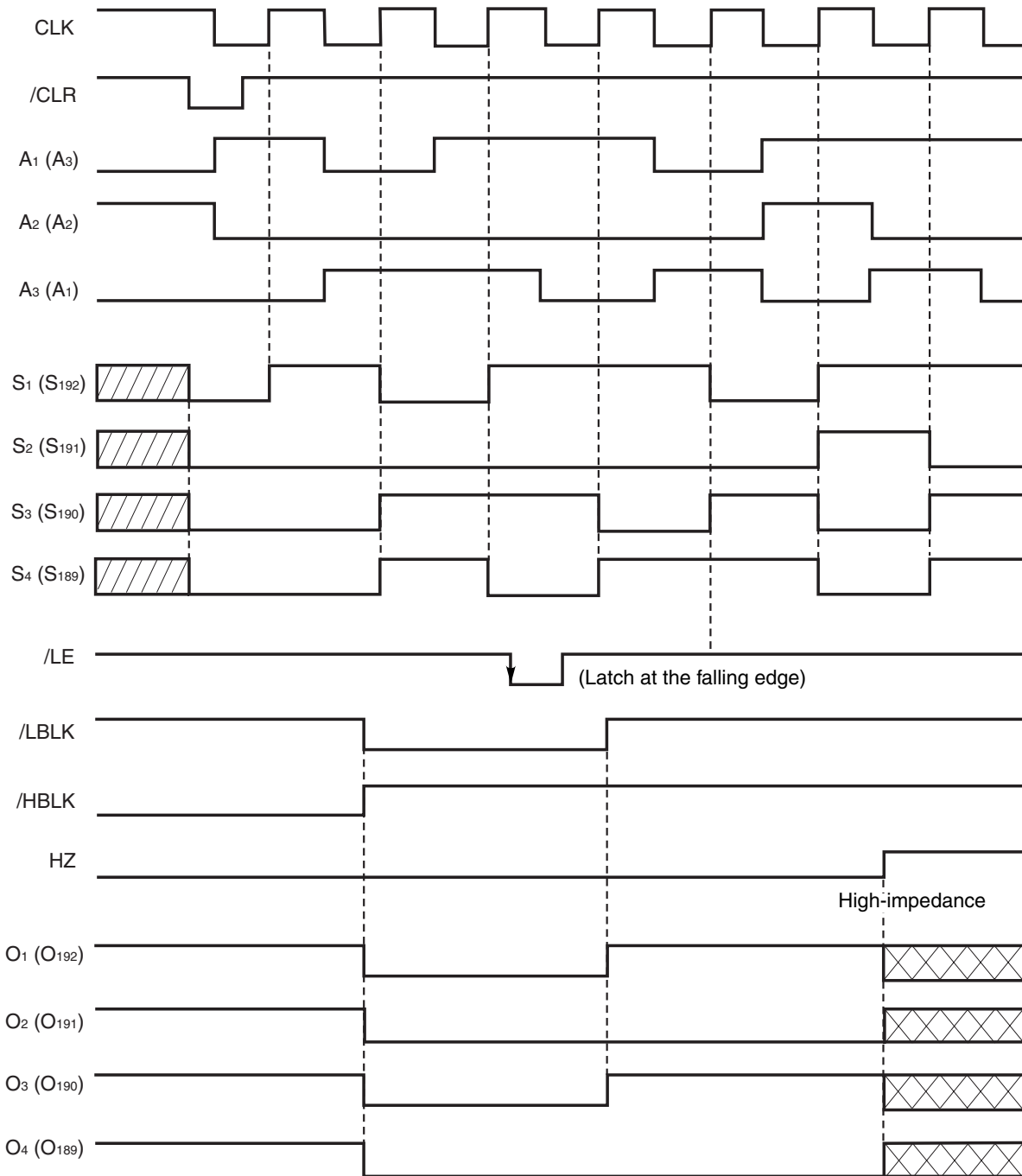
	3-bit Input	6-bit Input	6-bit (3-bit + 3-bit) Input
SR ₁ (A ₁ input register)	A ₁ → S ₁ , S ₄ ... S ₁₉₀	A ₁ → S ₁ , S ₇ ... S ₁₈₇	A ₁ → S ₁ , S ₄ ... S ₉₄
SR ₂ (A ₂ input register)	A ₂ → S ₂ , S ₅ ... S ₁₉₁	A ₂ → S ₂ , S ₈ ... S ₁₈₈	A ₂ → S ₂ , S ₅ ... S ₉₅
SR ₃ (A ₃ input register)	A ₃ → S ₃ , S ₆ ... S ₁₉₂	A ₃ → S ₃ , S ₉ ... S ₁₈₉	A ₃ → S ₃ , S ₆ ... S ₉₆
SR ₄ (A ₄ input register)		A ₄ → S ₄ , S ₁₀ ... S ₁₉₀	A ₄ → S ₉₇ , S ₁₀₀ ... S ₁₉₀
SR ₅ (A ₅ input register)		A ₅ → S ₅ , S ₁₁ ... S ₁₉₁	A ₅ → S ₉₈ , S ₁₀₁ ... S ₁₉₁
SR ₆ (A ₆ input register)		A ₆ → S ₆ , S ₁₂ ... S ₁₉₂	A ₆ → S ₉₉ , S ₁₀₂ ... S ₁₉₂

Shift Direction (R,/L = L, left shift)

	3-bit Input	6-bit Input	6-bit (3-bit + 3-bit) Input
SR ₁ (A ₁ input register)	A ₁ → S ₁₉₀ , S ₁₈₇ ... S ₁	A ₁ → S ₁₈₇ , S ₁₈₁ ... S ₁	A ₁ → S ₉₄ , S ₉₁ ... S ₁
SR ₂ (A ₂ input register)	A ₂ → S ₁₉₁ , S ₁₈₈ ... S ₂	A ₂ → S ₁₈₈ , S ₁₈₂ ... S ₂	A ₂ → S ₉₅ , S ₉₂ ... S ₂
SR ₃ (A ₃ input register)	A ₃ → S ₁₉₂ , S ₁₈₉ ... S ₃	A ₃ → S ₁₈₉ , S ₁₈₃ ... S ₃	A ₃ → S ₉₆ , S ₉₃ ... S ₃
SR ₄ (A ₄ input register)		A ₄ → S ₁₉₀ , S ₁₈₄ ... S ₄	A ₄ → S ₁₉₀ , S ₁₈₇ ... S ₉₇
SR ₅ (A ₅ input register)		A ₅ → S ₁₉₁ , S ₁₈₅ ... S ₅	A ₅ → S ₁₉₁ , S ₁₈₈ ... S ₉₈
SR ₆ (A ₆ input register)		A ₆ → S ₁₉₂ , S ₁₈₆ ... S ₆	A ₆ → S ₁₉₂ , S ₁₈₉ ... S ₉₉

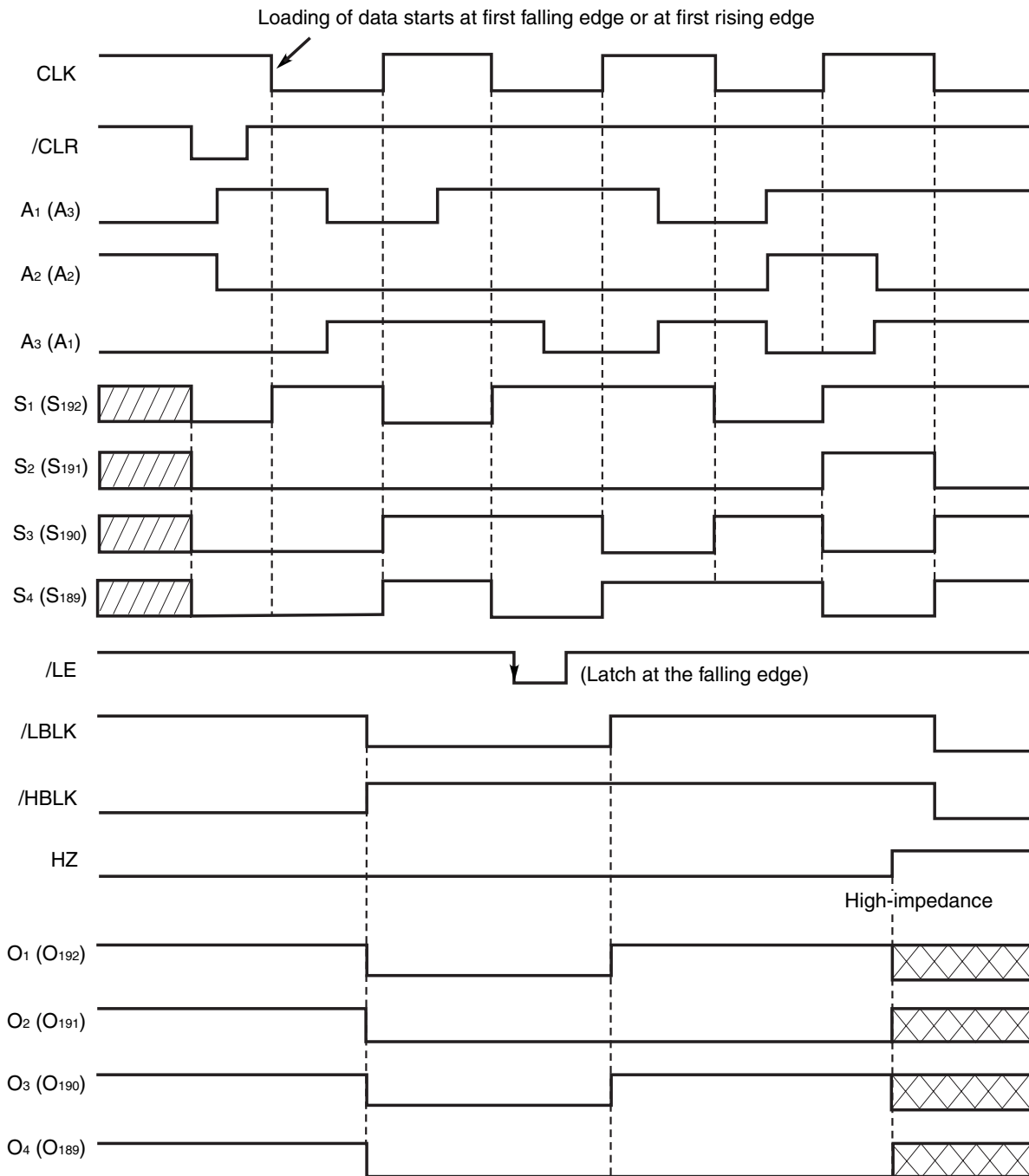
6. TIMING CHART

(1) IBS1 = L, IBS2 = H or L: 3-bit input, SDS = L: single edge



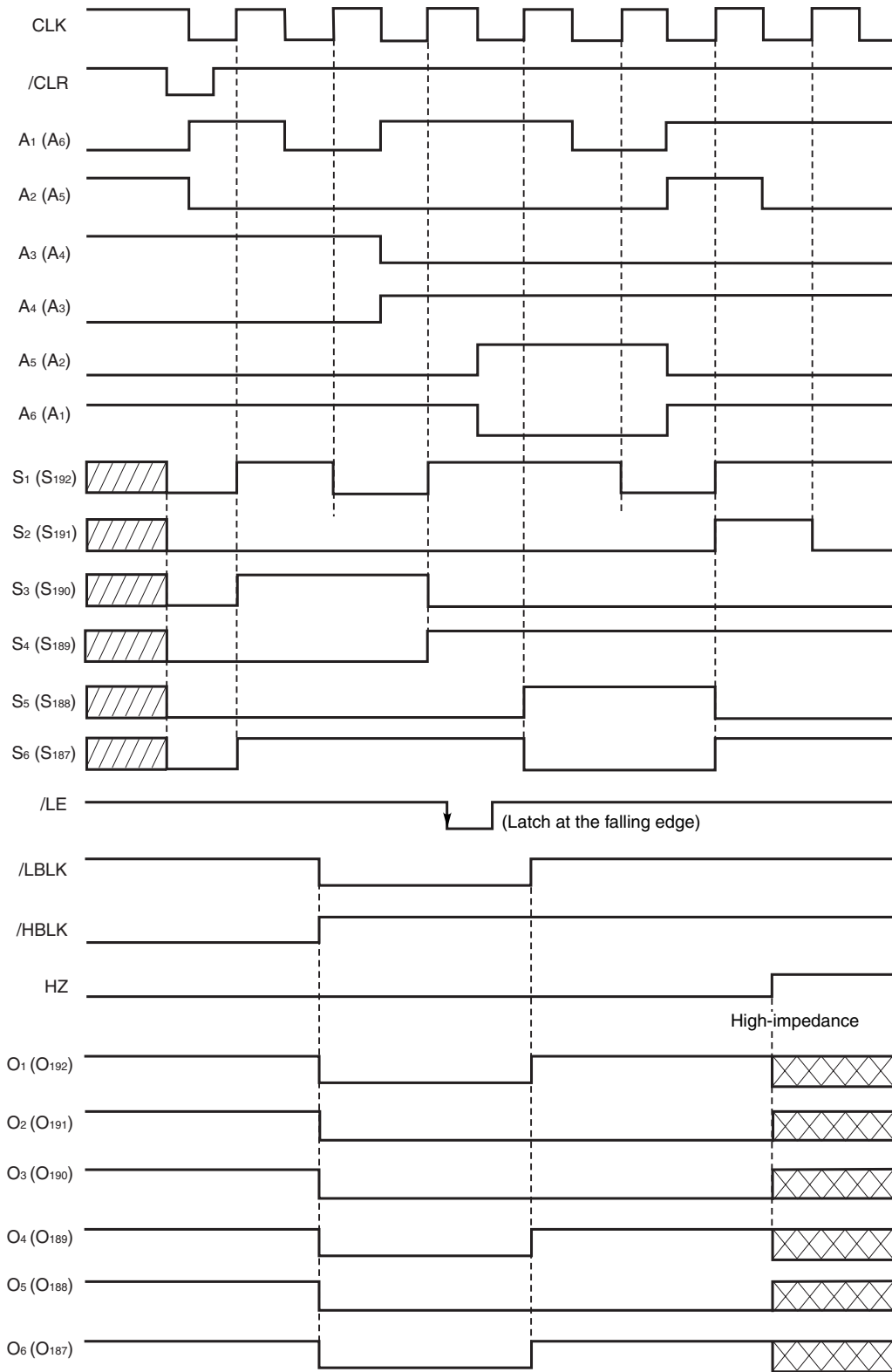
Remark Values in parentheses are when R/L = L.

(2) IBS1 = L, IBS2 = H or L: 3-bit input, SDS = H: double edge



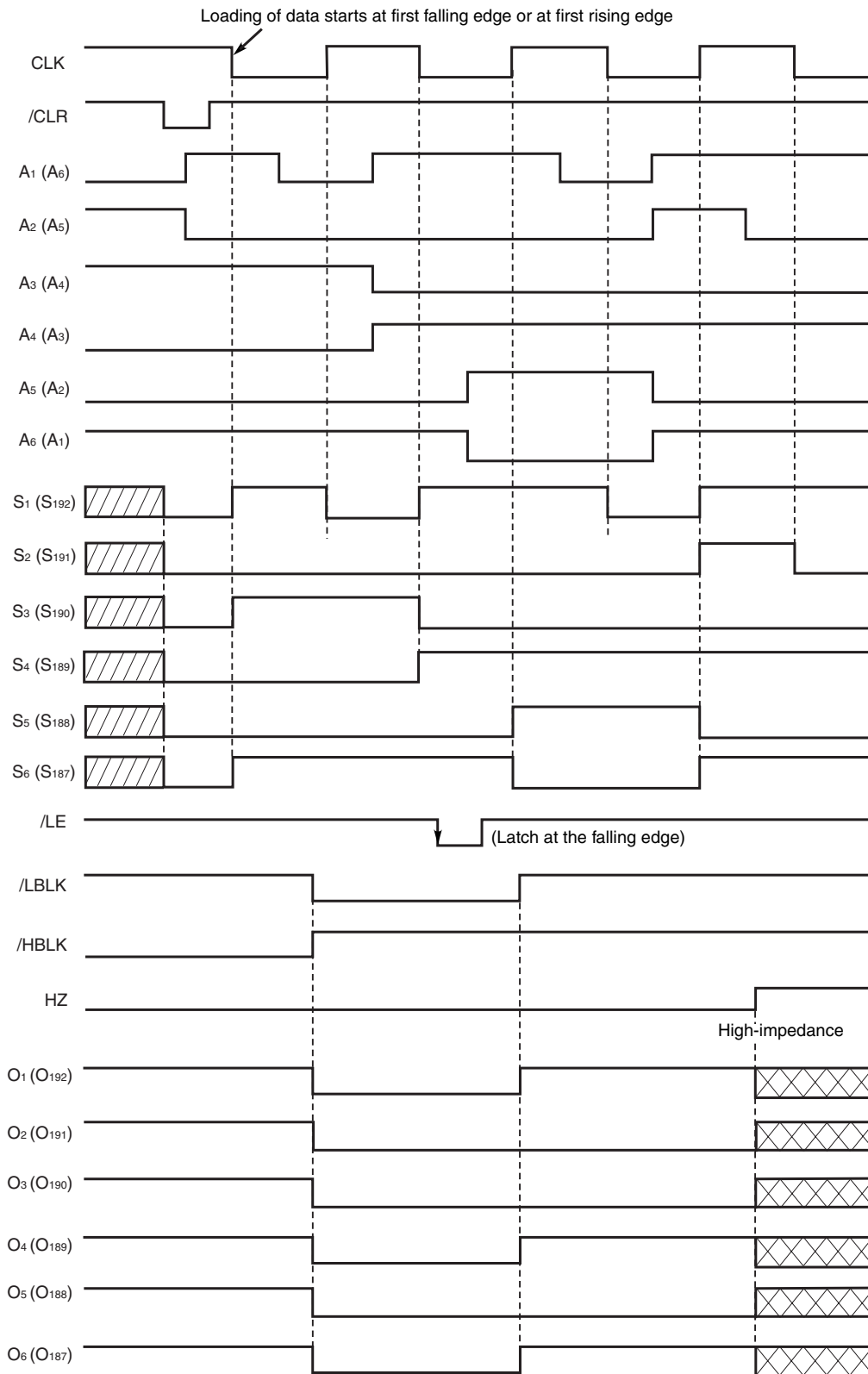
Remark Values in parentheses are when R,/L = L.

(3) IBS1 = H, IBS2 = L: 6-bit input, SDS = L: single edge



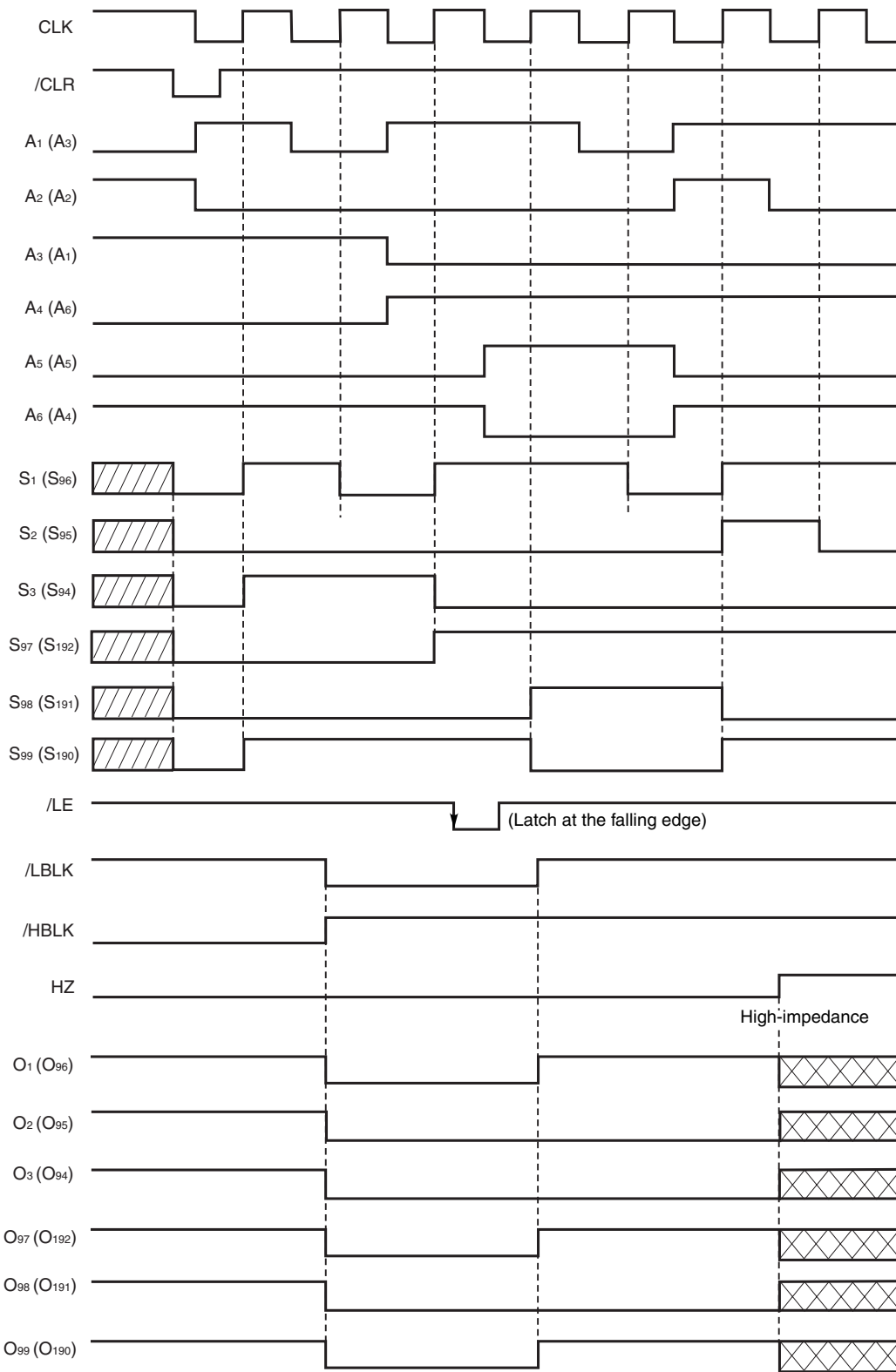
Remark Values in parentheses are when R,/L = L.

(4) IBS1 = H, IBS2 = L: 6-bit input, SDS = H: double edge



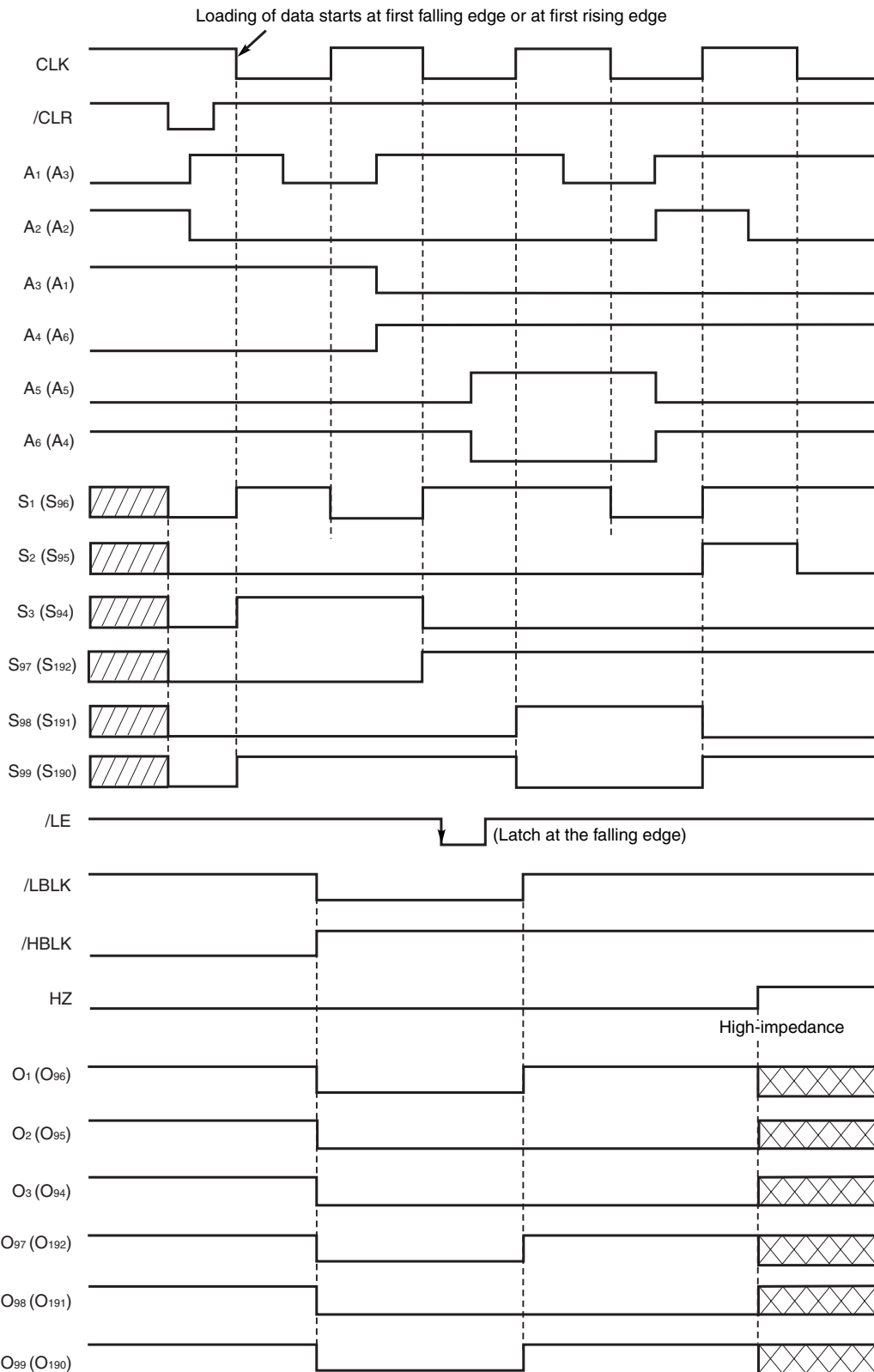
Remark Values in parentheses are when R,/L = L.

(5) IBS1 = H, IBS2 = H: 6-bit (3-bit + 3-bit) input, SDS = L: single edge



Remark Values in parentheses are when R,/L = L.

(6) IBS1 = H, IBS2 = H: 6-bit (3-bit + 3-bit) input, SDS = H: double edge



Remark Values in parentheses are when R,/L = L.

7. ELECTRICAL SPECIFICATIONS

Absolute Maximum Ratings (T_A = 25°C, V_{SS1} = V_{SS2} = 0 V)

Parameter	Symbol	Ratings	Unit
★ Logic supply voltage	V _{DD1}	-0.5 to +6.0	V
Driver supply voltage	V _{DD2}	-0.5 to +80	V
Logic input voltage	V _{I1}	-0.5 to V _{DD1} + 0.5	V
Operating junction temperature	T _j	+125	°C
Storage temperature	T _{stg}	-65 to +125	°C

Caution Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

Recommended Operating Range (T_A = -40 to +85°C, V_{SS1} = V_{SS2} = 0 V)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Logic supply voltage	V _{DD1}	4.75	5.0	5.25	V
Driver supply voltage	V _{DD2}	15		70	V
Logic high level input voltage	V _{IH11}	2.7		V _{DD1}	V
Logic low level input voltage	V _{IL11}	0		0.6	V
IBS and R,/L high level input voltage	V _{IH12}	0.7 V _{DD1}		V _{DD1}	V
IBS and R,/L low level input voltage	V _{IL12}	0		0.2 V _{DD1}	V
Driver output current	I _{OH2}			-24	mA
	I _{OL2}			+13	mA

Electrical Characteristics (T_A = 25°C, V_{DD1} = 5.0 V, V_{DD2} = 70 V, V_{SS1} = V_{SS2} = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
High level output voltage	V _{OH21}	I _{OH2} = -0.52 mA	69			V	
	V _{OH22}	I _{OH2} = -5.2 mA	65			V	
Low level output voltage	V _{OL21}	I _{OL2} = 1.6 mA			1.0	V	
	V _{OL22}	I _{OL2} = 13 mA			10	V	
Input leakage current	I _i	V _{I1} = V _{DD1} or V _{SS1}			±1.0	μA	
Logic high level input voltage	V _{IH11}	V _{DD1} = 4.75 to 5.25 V	2.7		V _{DD1}	V	
Logic low level input voltage	V _{IL11}	V _{DD1} = 4.75 to 5.25 V	0		0.6	V	
IBS and R,/L high level input voltage	V _{IH12}		0.7 V _{DD1}		V _{DD1}	V	
IBS and R,/L low level input voltage	V _{IL12}		0		0.2 V _{DD1}	V	
Static current dissipation	I _{DD11}	Logic, T _A = -40 to +85°C			1000 ^{Note1}	μA	
		Logic, T _A = 25°C			600 ^{Note1}	μA	
	I _{DD12}	Logic, T _A = -40 to +85°C			10 ^{Note2}	mA	
		Logic, T _A = 25°C			10 ^{Note2}	mA	
	I _{DD2}	Driver, T _A = -40 to +85°C				1000	μA
		Driver, T _A = 25°C				100	μA

Notes1. When input all input low level (But both the R,/L and IBS pins are fixed to V_I = V_{SS1} or V_{DD1})

2. When input all input high level (V_{IH} = 2.7 V to V_{DD1}, but both the R,/L and IBS pins are fixed to V_I = V_{SS1} or V_{DD1})

Switching Characteristics (T_A = 25°C, V_{DD1} = 5.0 V, V_{DD2} = 70 V, V_{SS1} = V_{SS2} = 0 V, logic C_L = 15 pF,

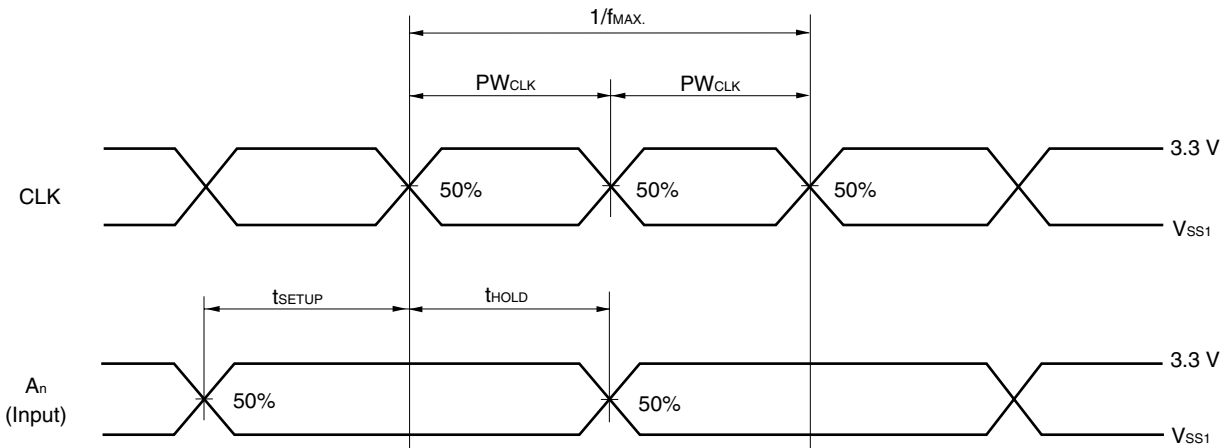
driver C_L = 50 pF, t_r = t_f = 3.0 ns)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Propagation delay time	t _{PHL2}	/LE ↓ → O ₁ to O ₁₉₂			220	ns
	t _{PLH2}				220	ns
	t _{PHL3}	/HBLK → O ₁ to O ₁₉₂			205	ns
	t _{PLH3}				205	ns
	t _{PHL4}	/LBLK → O ₁ to O ₁₉₂			200	ns
	t _{PLH4}				200	ns
	t _{PHZ}	HZ → O ₁ to O ₁₉₂ , R _L = 10 kΩ			340	ns
	t _{PZH}				220	ns
	t _{PLZ}				340	ns
	t _{PZL}				220	ns
Rise time	t _{TLH}	O ₁ to O ₁₉₂			220	ns
	t _{TLZ}	O ₁ to O ₁₉₂ , R _L = 10 kΩ			3	μs
	t _{TZH}				220	ns
Fall time	t _{THL}	O ₁ to O ₁₉₂			350	ns
	t _{THZ}	O ₁ to O ₁₉₂ , R _L = 10 kΩ			3	μs
	t _{TZL}				350	ns
Clock frequency	f _{CLK}	Loading of data, duty = 50%			60	MHz
Input capacitance	C _I				15	pF

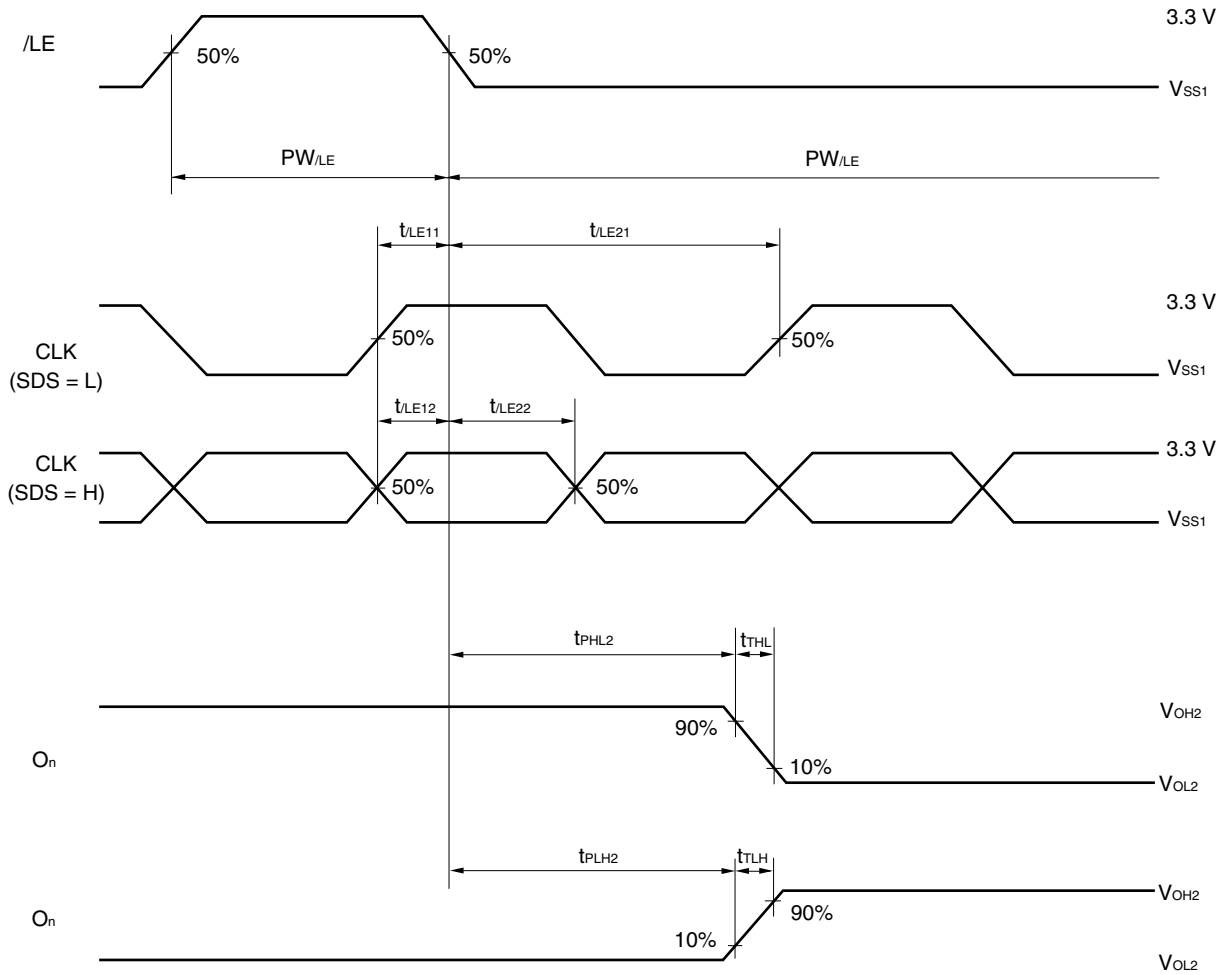
Timing Requirement (T_A = 25°C, V_{DD1} = 4.75 to 5.25 V, V_{SS1} = V_{SS2} = 0 V, t_r = t_f = 3.0 ns)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Clock pulse width	PW _{CLK}		8			ns
Latch enable pulse width	PW _{/LE}		8			ns
Blank pulse width	PW _{/BLK}	/HBLK, /LBLK	600			ns
HZ pulse width	PW _{HZ}	R _L = 10 kΩ	3.3			μs
/CLR pulse width	PW _{/CLR}		12			ns
/CLR timing	t _{/CLR}		6			ns
Data setup time	t _{SETUP}		3			ns
Data hold time	t _{HOLD}		3			ns
Latch enable Time	t _{LE11} , t _{LE21}		8			ns
	t _{LE12} , t _{LE22}		8			ns

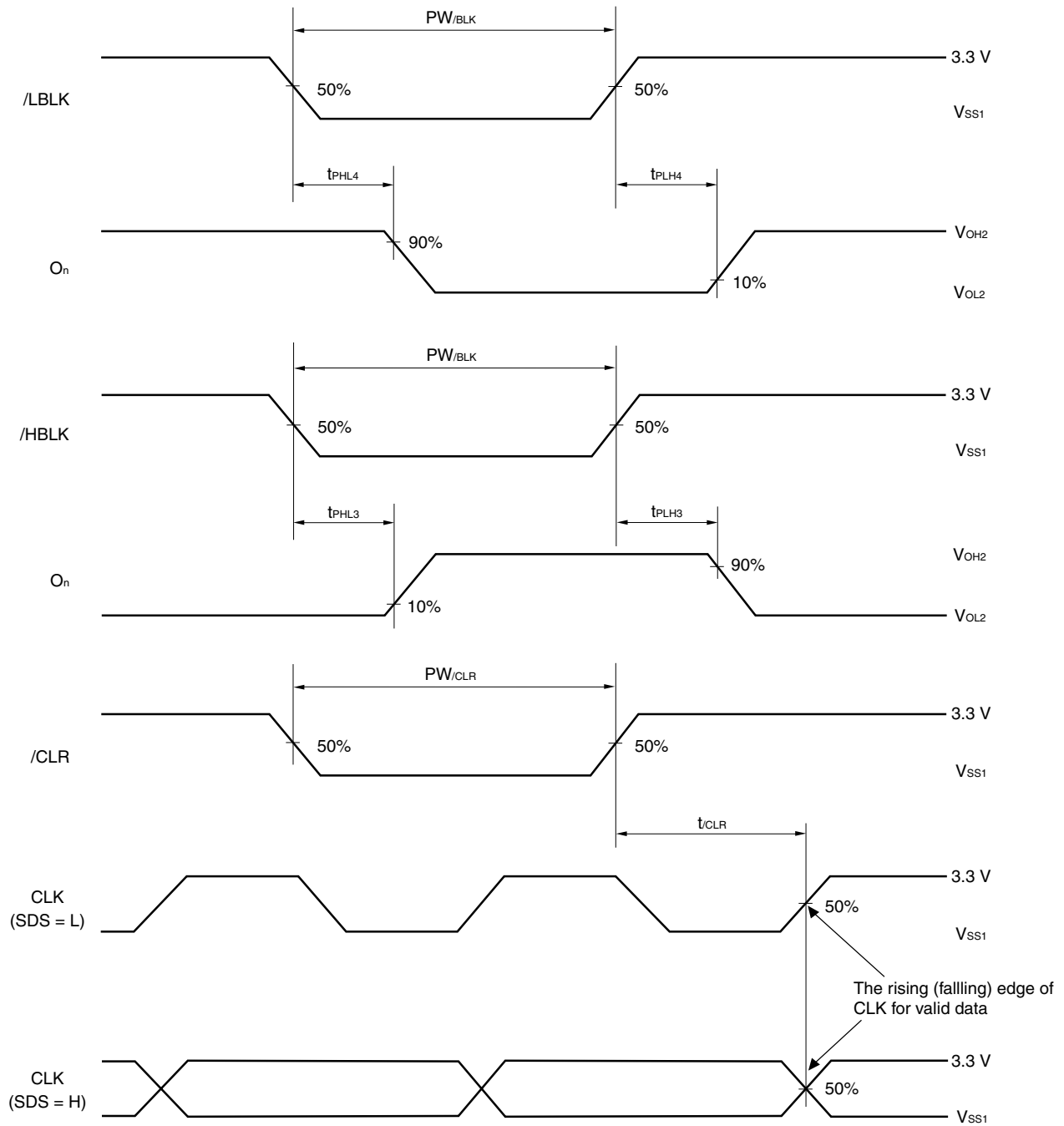
Switching Characteristics Waveform (1/3)



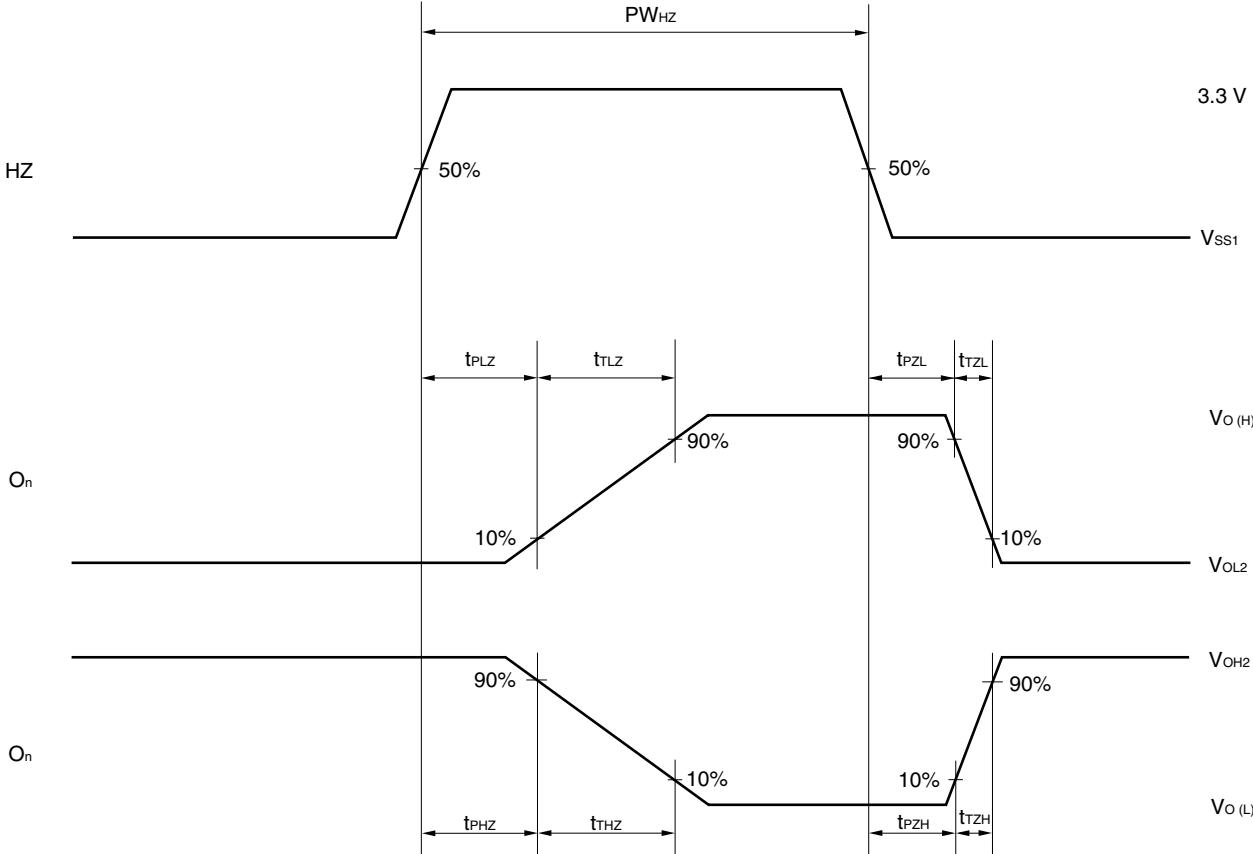
Remark The falling timing of CLK is at SDS = H (double edge).



Switching Characteristics Waveform (2/3)



Switching Characteristics Waveform (3/3)



8. RECOMMENDED MOUNTING CONDITIONS

The following conditions must be met of mounting conditions of the μ PD160300.

For more details, refer to the **Semiconductor Device Mount Manual** (<http://www.necel.com/pkg/en/mount/index.html>).

Please consult with our sales offices in case other mounting process is used, or in case the mounting is done under different conditions.

μ PD160300N-xxx: TCP (TAB Package)

Mounting Condition	Mounting Method	Condition
Thermocompression	Soldering	Heating tool 300 to 350°C, heating for 2 to 3 seconds : pressure 100g (per solder)
	ACF (Adhesive Conductive Film)	Temporary bonding 70 to 100°C: pressure 3 to 8 kg/cm ² : time 3 to 5 sec. Real bonding 165 to 180°C: pressure 25 to 45 kg/cm ² : time 30 to 40 sec. (When using the anisotropy conductive film SUMIZAC1003 of Sumitomo Bakelite,Ltd).

Caution To find out the detailed conditions for mounting the ACF part, please contact the ACF manufacturing company. Be sure to avoid using two or more mounting methods at a time.

NOTES FOR CMOS DEVICES**① VOLTAGE APPLICATION WAVEFORM AT INPUT PIN**

Waveform distortion due to input noise or a reflected wave may cause malfunction. If the input of the CMOS device stays in the area between V_{IL} (MAX) and V_{IH} (MIN) due to noise, etc., the device may malfunction. Take care to prevent chattering noise from entering the device when the input level is fixed, and also in the transition period when the input level passes through the area between V_{IL} (MAX) and V_{IH} (MIN).

② HANDLING OF UNUSED INPUT PINS

Unconnected CMOS device inputs can be cause of malfunction. If an input pin is unconnected, it is possible that an internal input level may be generated due to noise, etc., causing malfunction. CMOS devices behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using pull-up or pull-down circuitry. Each unused pin should be connected to V_{DD} or GND via a resistor if there is a possibility that it will be an output pin. All handling related to unused pins must be judged separately for each device and according to related specifications governing the device.

③ PRECAUTION AGAINST ESD

A strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it when it has occurred. Environmental control must be adequate. When it is dry, a humidifier should be used. It is recommended to avoid using insulators that easily build up static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work benches and floors should be grounded. The operator should be grounded using a wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with mounted semiconductor devices.

④ STATUS BEFORE INITIALIZATION

Power-on does not necessarily define the initial status of a MOS device. Immediately after the power source is turned ON, devices with reset functions have not yet been initialized. Hence, power-on does not guarantee output pin levels, I/O settings or contents of registers. A device is not initialized until the reset signal is received. A reset operation must be executed immediately after power-on for devices with reset functions.

Reference Documents

NEC Semiconductor Device Reliability/Quality Control System (C10983E)

Quality Grades On NEC Semiconductor Devices (C11531E)

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